



# BT1308W series D

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Triacs logic level

Rev. 01 — 27 February 2008

Product data sheet

## 1. Product profile

### 1.1 General description

Passivated sensitive gate triacs in a SOT223 surface-mountable plastic package

### 1.2 Features

- Sensitive gate
- Direct interfacing to logic level ICs
- Gate triggering in four quadrants
- Direct interfacing to low-power gate drive circuits

### 1.3 Applications

- General purpose switching and phase control
- Low-power AC fan speed controllers

### 1.4 Quick reference data

- $V_{DRM} \leq 400$  V (BT1308W-400D)
- $V_{DRM} \leq 600$  V (BT1308W-600D)
- $I_{TSM} \leq 9$  A ( $t = 20$  ms)
- $I_{GT} \leq 5$  mA
- $I_{GT} \leq 7$  mA (T2– G+)
- $I_{T(RMS)} \leq 0.8$  A

## 2. Pinning information

Table 1. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	main terminal 1 (T1)		
2	main terminal 2 (T2)		
3	gate (G)		
4	mounting base; main terminal 2 (T2)		

## 3. Ordering information

**Table 2. Ordering information**

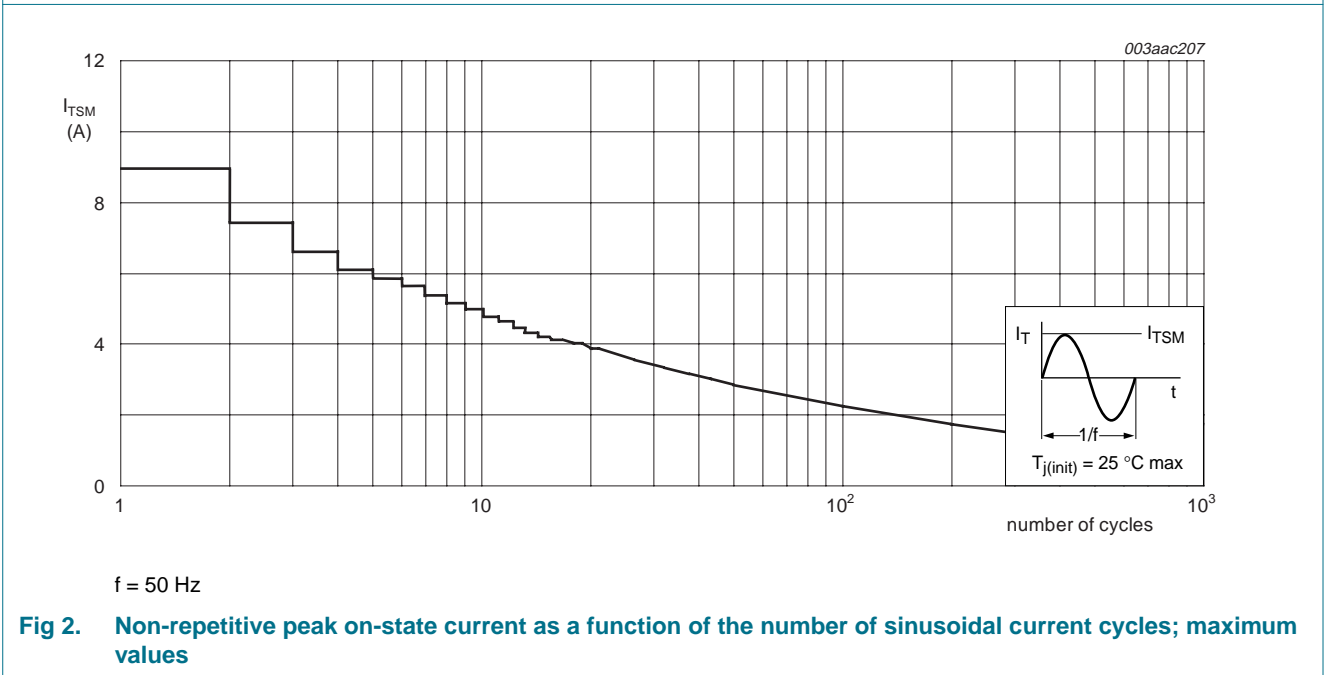
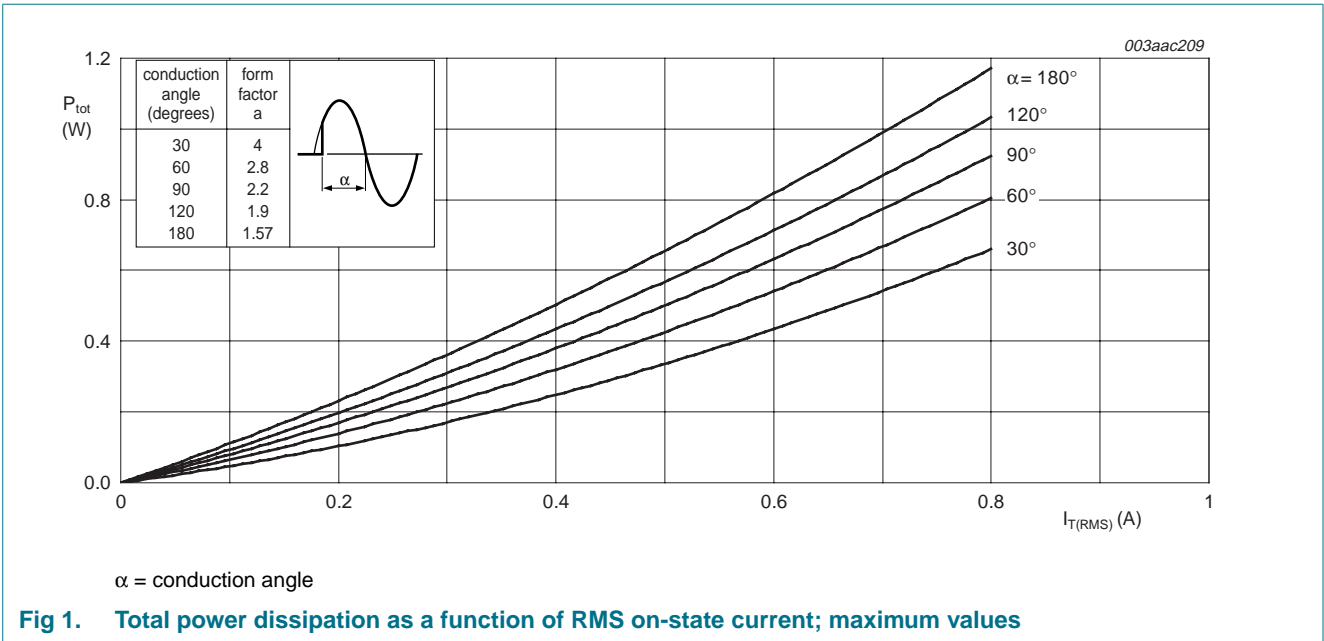
Type number	Package		Version
	Name	Description	
BT1308W-400D	SC-73	plastic surface-mounted package with increased heatsink; 4 leads	SOT223
BT1308W-600D			

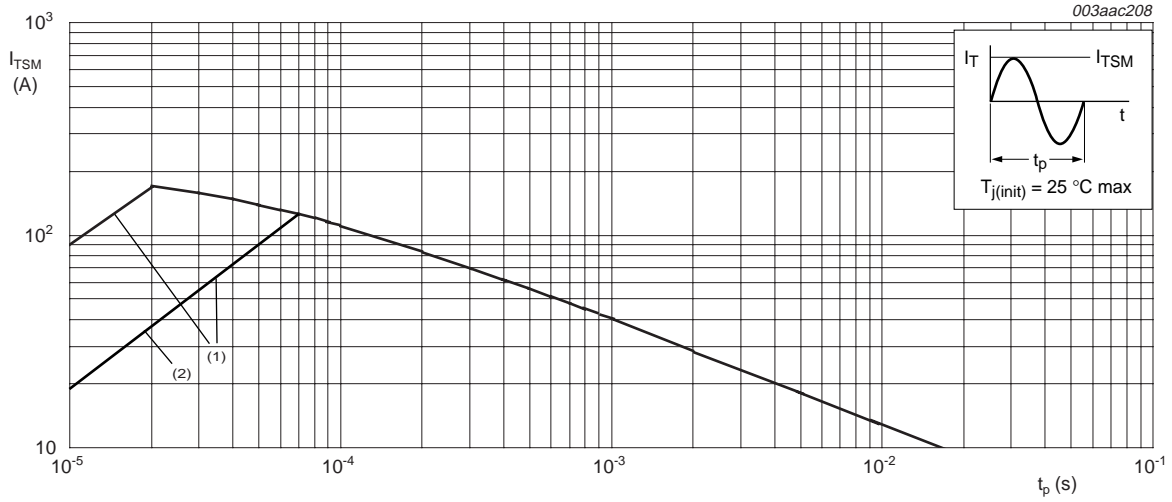
## 4. Limiting values

**Table 3. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

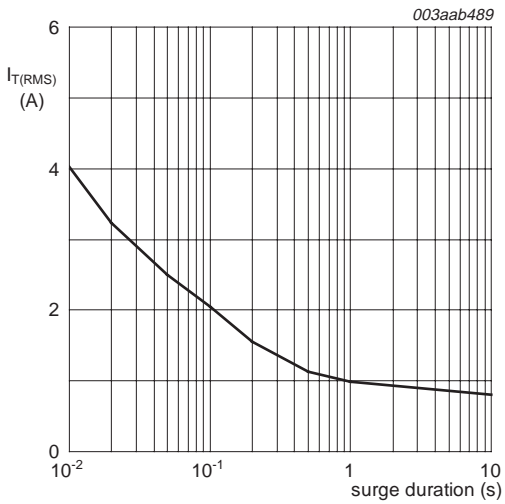
Symbol	Parameter	Conditions	Min	Max	Unit
$V_{\text{DRM}}$	repetitive peak off-state voltage	BT1308W-400D	-	400	V
		BT1308W-600D	-	600	V
$I_{\text{T(RMS)}}$	RMS on-state current	full sine wave; $T_{\text{sp}} \leq 107.4\text{ °C}$ ; see <a href="#">Figure 4</a> and <a href="#">5</a>	-	0.8	A
$I_{\text{TSM}}$	non-repetitive peak on-state current	full sine wave; $T_{\text{j}} = 25\text{ °C}$ prior to surge; see <a href="#">Figure 2</a> and <a href="#">3</a>			
		$t = 20\text{ ms}$	-	9	A
		$t = 16.7\text{ ms}$	-	10	A
$I^2t$	$I^2t$ for fusing	$t_{\text{p}} = 10\text{ ms}$	-	0.32	$\text{A}^2\text{s}$
$di_{\text{T}}/dt$	rate of rise of on-state current	$I_{\text{TM}} = 1\text{ A}$ ; $I_{\text{G}} = 20\text{ mA}$ ; $di_{\text{G}}/dt = 0.2\text{ A}/\mu\text{s}$			
		T2+ G+	-	50	$\text{A}/\mu\text{s}$
		T2+ G-	-	50	$\text{A}/\mu\text{s}$
		T2- G-	-	50	$\text{A}/\mu\text{s}$
		T2- G+	-	10	$\text{A}/\mu\text{s}$
$I_{\text{GM}}$	peak gate current		-	1	A
$P_{\text{GM}}$	peak gate power		-	5	W
$P_{\text{G(AV)}}$	average gate power	over any 20 ms period	-	0.1	W
$T_{\text{stg}}$	storage temperature		-40	+150	$^{\circ}\text{C}$
$T_{\text{j}}$	junction temperature		-	125	$^{\circ}\text{C}$





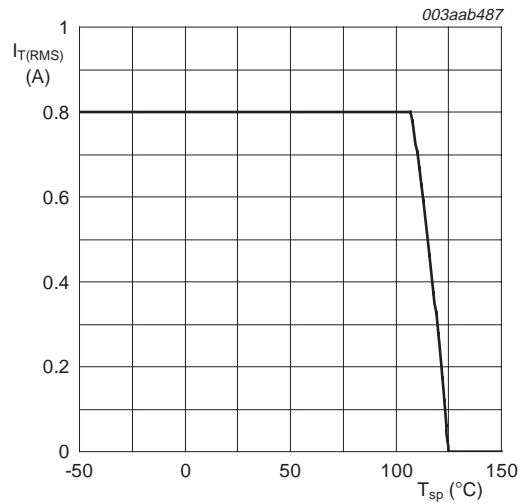
- $t_p \leq 20$  ms
- (1)  $dI_T/dt$  limit
  - (2) T2- G+ quadrant limit

**Fig 3. Non-repetitive peak on-state current as a function of pulse width; maximum values**



$f = 50$  Hz  
 $T_{sp} = 107.4$  °C

**Fig 4. RMS on-state current as a function of surge duration; maximum values**

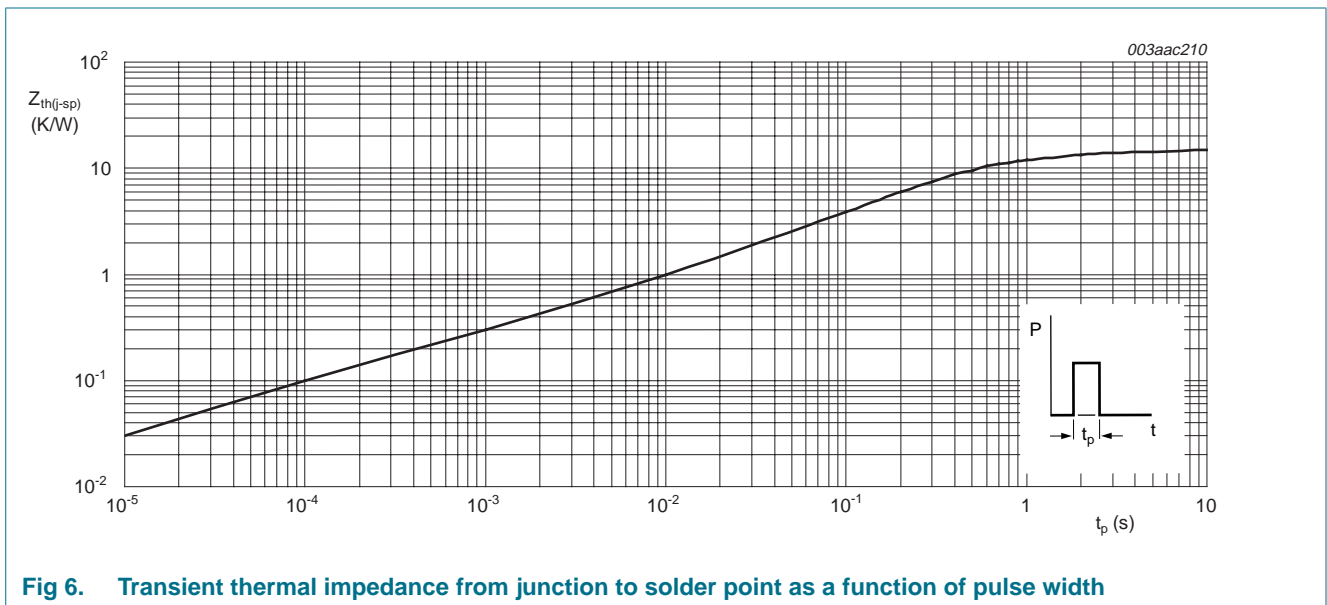


**Fig 5. RMS on-state current as a function of solder point temperature; maximum values**

## 5. Thermal characteristics

**Table 4. Thermal characteristics**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-sp)}$	thermal resistance from junction to solder point	full cycle; see <a href="#">Figure 6</a>	-	-	15	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	full cycle				
		for minimum footprint; see <a href="#">Figure 13</a>	-	156	-	K/W
		for pad area; see <a href="#">Figure 14</a>	-	70	-	K/W

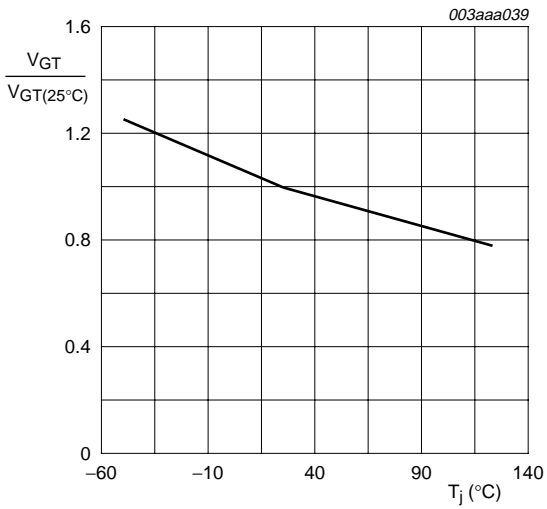


## 6. Characteristics

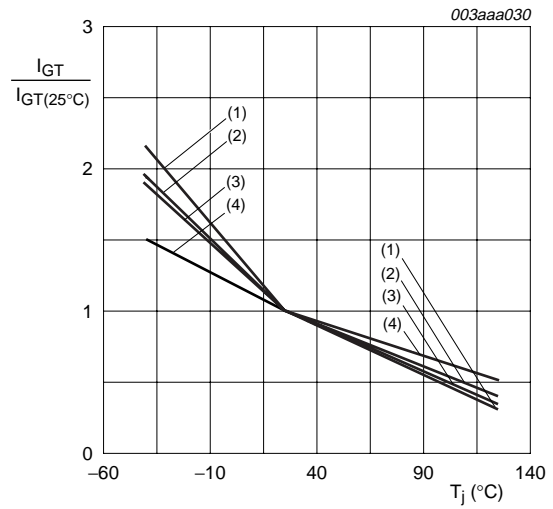
**Table 5. Characteristics**

$T_j = 25\text{ °C}$  unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Static characteristics</b>						
$I_{GT}$	gate trigger current	$V_D = 12\text{ V}$ ; $I_T = 0.1\text{ A}$ ; see <a href="#">Figure 8</a>				
		T2+ G+	-	1	5	mA
		T2+ G-	-	2	5	mA
		T2- G-	-	2	5	mA
		T2- G+	-	4	7	mA
$I_L$	latching current	$V_D = 12\text{ V}$ ; $I_G = 0.1\text{ A}$ ; see <a href="#">Figure 10</a>				
		T2+ G+	-	1	10	mA
		T2+ G-	-	5	10	mA
		T2- G-	-	1	10	mA
		T2- G+	-	2	10	mA
$I_H$	holding current	$V_D = 12\text{ V}$ ; $I_G = 0.1\text{ A}$ ; see <a href="#">Figure 11</a>	-	1	10	mA
$V_T$	on-state voltage	$I_T = 0.85\text{ A}$ ; see <a href="#">Figure 9</a>	-	1.35	1.6	V
$V_{GT}$	gate trigger voltage	$V_D = 12\text{ V}$ ; $I_T = 0.1\text{ A}$ ; see <a href="#">Figure 7</a>	-	0.9	2	V
		$V_D = V_{DRM}$ ; $I_T = 0.1\text{ A}$ ; $T_j = 110\text{ °C}$	0.1	0.7	-	V
$I_D$	off-state current	$V_D = V_{DRM(max)}$ ; $T_j = 125\text{ °C}$	-	0.1	0.5	mA
<b>Dynamic characteristics</b>						
$dV_D/dt$	rate of rise of off-state voltage	$V_{DM} = 0.67 \times V_{DRM(max)}$ ; $T_j = 110\text{ °C}$ ; exponential waveform; gate open circuit	30	45	-	V/ $\mu$ s
$dV_{com}/dt$	rate of change of commutating voltage	$V_{DM} = V_{DRM(max)}$ ; $T_j = 50\text{ °C}$ ; $I_{TM} = 0.84\text{ A}$ ; $dI_{com}/dt = 0.3\text{ A/ms}$	-	5	-	V/ $\mu$ s
$t_{gt}$	gate-controlled turn-on time	$I_{TM} = 1\text{ A}$ ; $V_D = V_{DRM(max)}$ ; $I_G = 25\text{ mA}$ ; $dI_G/dt = 5\text{ A}/\mu$ s	-	2	-	$\mu$ s

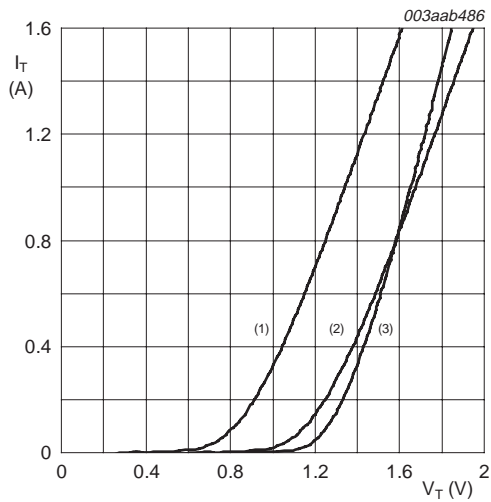


**Fig 7. Normalized gate trigger voltage as a function of junction temperature**



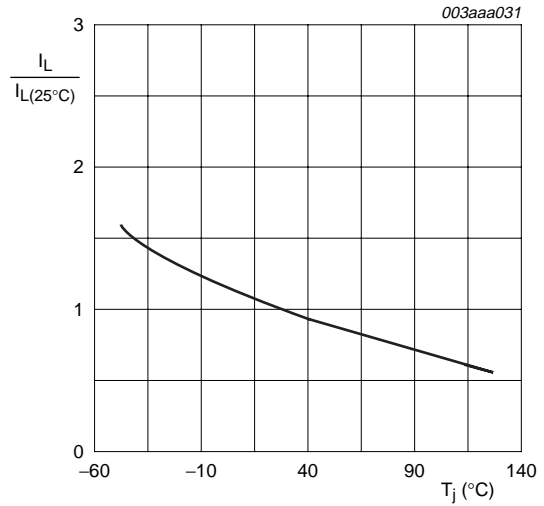
- (1) T2+ G+
- (2) T2- G+
- (3) T2- G-
- (4) T2+ G-

**Fig 8. Normalized gate trigger current as a function of junction temperature**

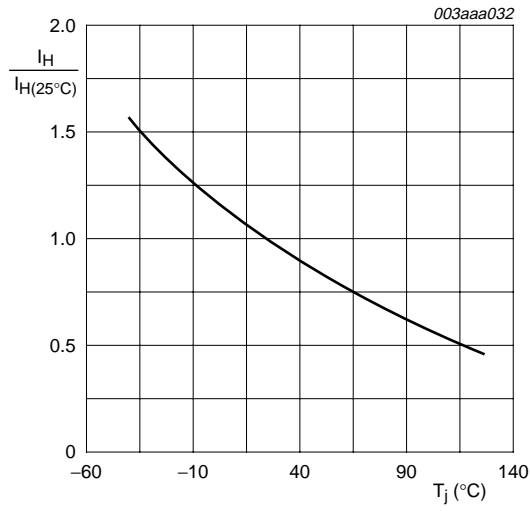


- $V_o = 1.171 \text{ V}$   
 $R_s = 0.5125 \text{ } \Omega$
- (1)  $T_j = 125 \text{ } ^\circ\text{C}$ ; typical values
  - (2)  $T_j = 125 \text{ } ^\circ\text{C}$ ; maximum values
  - (3)  $T_j = 25 \text{ } ^\circ\text{C}$ ; maximum values

**Fig 9. On-state current as a function of on-state voltage**



**Fig 10. Normalized latching current as a function of junction temperature**



**Fig 11. Normalized holding current as a function of junction temperature**



**7. Package outline**

Plastic surface-mounted package with increased heatsink; 4 leads

SOT223

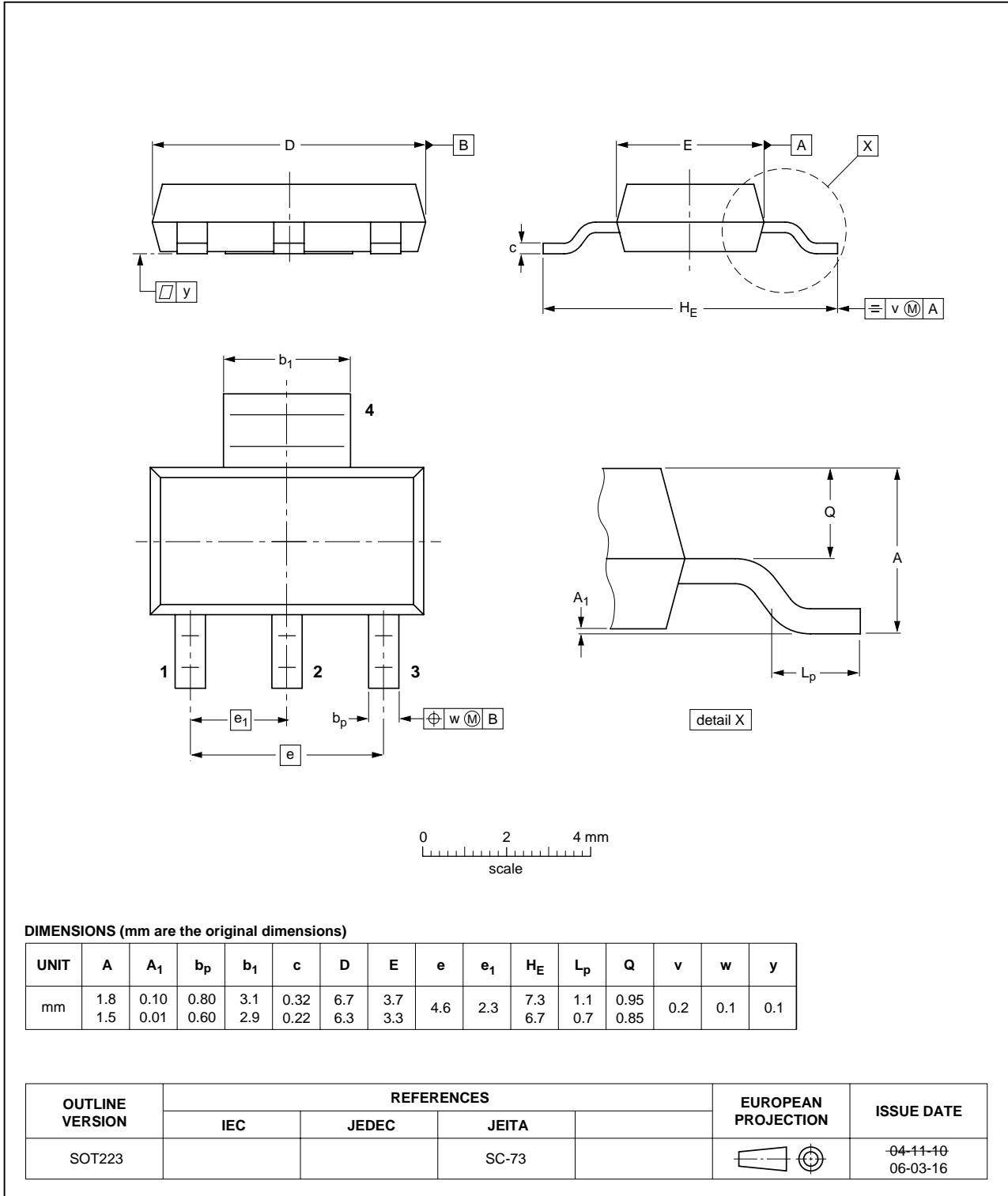
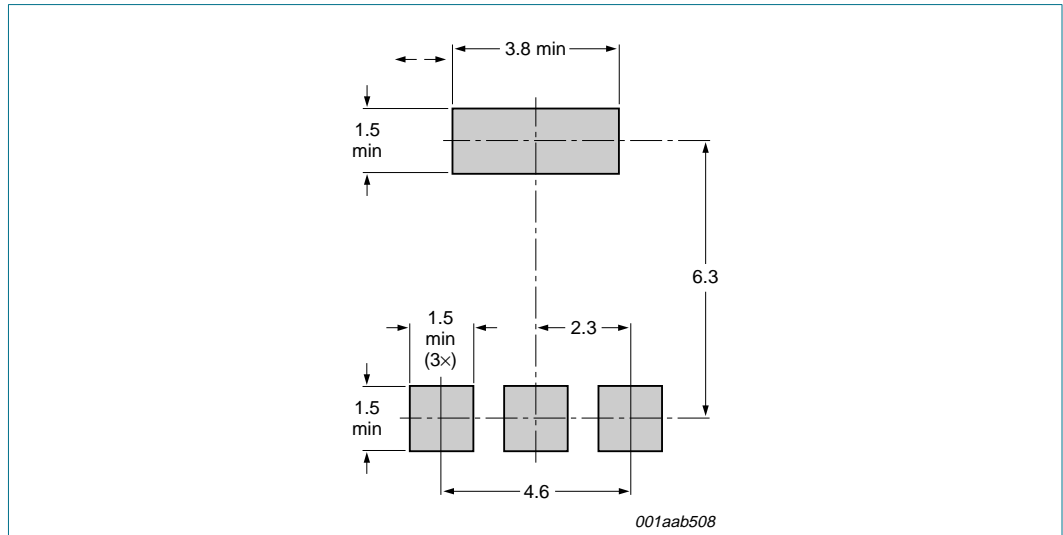


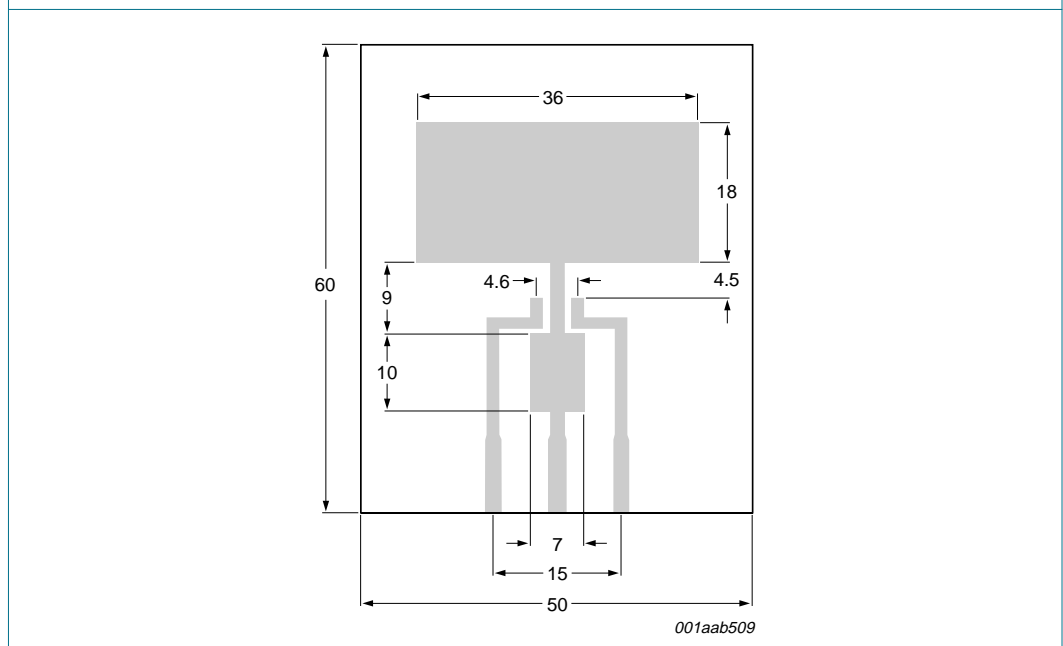
Fig 12. Package outline SOT223 (SC-73)

## 8. Mounting



All dimensions are in mm.

**Fig 13. Minimum footprint SOT223**



All dimensions are in mm.

Printed circuit board: FR4 epoxy glass (1.6 mm thick), copper laminate (35 µm thick).

**Fig 14. Printed circuit board pad area SOT223**

## 9. Revision history

Table 6. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BT1308W_SER_D_1	20080227	Product data sheet	-	-

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Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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 Date of release: 27 February 2008  
 Document identifier: BT1308W\_SER\_D\_1